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1. % getJ: function description dx, meff, Ec, Ez
2. function J = getJ(dx, meff, Ec, dU, EFermi)
3.     e = 1.6e-19; eVtoJ = e; JtoEv = e^(-1);
4.     hbar = 1.054*1e-34; k_B = 1.38e-23;
5.     T = 300;
6.     kT = T*k_B;
7.
8.     k = ((2*meff(1)*e*kT)/(4*pi^2*hbar^3));
9.     J = k*ones(1, length(dU));
10.
11. % Count layers
12. % Reserves
13. r = 5;
14. % Active field
15. a = 8; % monolayers
16. b = 5;
17. c = 6;
18.
19. % ni = 1e12;
20. % Nd = 1e24;
21. % Ni = [Nd*ones(1, r), ni*ones(1, a), ni*ones(1, b), ni*ones(1, c), ni*ones(1, b), ni*ones(1, a),
Nd*ones(1, r)];
22.
23. % eps = 13.18 - 3.12*[zeros(1, r), zeros(1, a), ones(1, b), zeros(1, c), ones(1, b), zeros(1, a),
zeros(1, r)];
24.
25. for j = 1:length(dU)
26.     % [V, n] = getConcentrationElectrons(0.0001, [Ec(1)*ones(1, r), Ec, Ec(end)*ones(1, r)]*eVtoJ,
[meff(1)*ones(1, r), meff, meff(end)*ones(1, r)], Ni, eps, dx, dU(j), r + 1, r + length(Ec));
27.     % Uj = Ec - linspace( 0, dU(j), length(Ec) ) - V(r+1:length(Ec)+r)*eVtoJ;
28.     Uj = Ec - linspace( 0, dU(j), length(Ec) );
29.     dTDEz = @(Ez) TDEz(dx, meff, Uj, Ez, EFermi);
30.     J(j) = J(j)*integral(dTDEz, 0, max(Uj), 'AbsTol', 1e-30);
31. end
32. end

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